

# Study the Effect of Cold Plasma on the Structure and Surface Properties of PbO Thin Film

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**Abstract:** *In this research, the structural and surface property of lead oxide thin films (PbO) has been studied. They were prepared by the chemical Spray Pyrolysis method on glass substrates at (450°C).the structural properties has been studied using X-ray diffraction (XRD) analysis and the surface properties of the thin film where investigated using atomic force microscopy AFM analysis before and after the subjection of the thin film to cold plasma at different times (5, 10, 15, 20, 25) min. dielectric barrier discharge system were used to generate the cold plasma. The results of (XRD) tests showed that all the prepared films were of a polycrystalline and the thickness of the thin film is slightly decreases when subjected to cold plasma and the average of crystal size rates increasing too. The pictures of atomic force microscope (AFM) showed the values of the average of the surface roughness and the square root (RMS) increases as time of treatment increase*

**Keywords:** lead oxide, chemical spray pyrolysis, structural properties, surface properties, cold plasma

## 1. Introduction

Thin film technology is one of the most important technologies that contributed to the development of the semiconductor study. It gave a clear idea of many of its physical and chemical properties, and it differs from the material in its bulk condition. It is not completely dense and has different defect structures. The thin membrane is defined as a layer of layers of material atoms the thickness of one micron [1], [2]

The study of thin films has attracted the attention of many researchers since the nineteenth century, as there has been a lot of important research in this area.

The term thin films are used to describe one or several layers of atoms of a specific material that does not exceed several microns. The thickness of thin films is easy to crack, resulting in their deposition on different materials depending on the nature of the study such as glass, quartz and silicon.

Plasma is defined as a semi-neutral gas of charged and neutral particles that exhibit collective behavior [6], [5]. Plasma is classified into two main categories: high temperature plasma (plasma fusion) and low temperature plasma (gas discharge) or non-thermal plasma [7]

Non-thermal plasma is the state of which ions and neutral particles have the same temperature surrounding them, but the temperature of electrons is much higher. Most of the energy processed in the cold plasma turns into electrons in the plasma, thus producing effective electrons instead of heating the gas in general. Ions and neutral particles are relatively cold. They have been used in the treatment of thermally sensitive materials, including polymers and biologics [8], and in various industrial and scientific applications. [9] And tissue [10]. The plasma has been

generated by the barrier technique (DBD), which is widely used in a large number of industrial applications and technology. It is characterized by the other types of discharge that it works for the production of non-thermal plasma at atmospheric pressure. This technique is used in the applications of surface treatment [11]

A thin membrane of lead oxides (PbO) was introduced and exposed to non - thermal plasma at different times and studied the nature of the surface after treatment. XRD and AFM were used in studying the changes that occur on surface of the membranes.

## 2. Experimental

### A. Sample preparation and deposition procedure

The PbO thin films were prepared by spraying an aqueous solution of Lead (II) acetate trihydrate. This solution of 0.1M was prepared by dissolving 1.899 gm of  $Pb(CH_3COO)_2 \cdot 3H_2O$  [which is a powder of white color, it's molecular weight (379.33 g/mol)] in 50 ml distilled water. The weights of  $[Pb(CH_3COO)_2 \cdot 3H_2O]$  were measured by using sensitive electrical balance of four digits (10<sup>-4</sup> g).the solutions was mixed with magnetic stirrer for 10-15 min to complete the dissolving process and left for 1 hour to get a homogenous solution at temperature of 450 °C. Using the spray pyrolysis method to prepare the thin film on a glass base .the durance time to spray was 5 sec and then stop for 55 sec. when the drop of solution reach the hot solid surface the water evaporate and the reaction occur to form the PbO thin film

### B. Treatment with Cold Plasma

Dielectric barrier discharge system consist of two cylindrical electrode made of copper with diameter (50 mm), the electrode was surrounding by Teflon with thickness (10 mm). The two electrodes were fixed such that one of them can be

moved vertically to change the distance between the electrodes. The two electrodes were connected to high power Ac voltage. One of the electrodes was covered by dielectric material. The instrument is shown in figure



Figure 1: Dielectric barrier discharge system

The PbO thin films were placed between the two electrode which they were departed at distance of 2 mm and the plasma were generated at AC voltage ..... The thin films were subjected to the cold plasma at different times (5, 10, 15, 20, 25) min. After the treatment the samples were taken for XRD and AFM analysis

### 3. Results and Discussions

#### A. XRD result

The X-ray Diffraction investigation has been carried out for thin films (PbO) as shown in Fig. (2), for range of  $2\theta$  from  $15^\circ$ - $75^\circ$ . According to phase identification software (Match!), the prepared thin film sample has the sample diffraction pattern of reference[10]the rest of the matched data are shown in figure (3) such as the cell parameters  $a = b = 3.9748 \text{ \AA}$  and  $c = 5.0227 \text{ \AA}$  .the structure of these films showed a polycrystalline structure with crystal system of tetragonal. The interplaner spacing (dhk1) was determined using the Bragg relationship [62].

$$2d \sin\theta = n \lambda \quad (1)$$

Where n is an integer that indicates the order of the reflection,  $\theta$  is Bragg angle, and  $\lambda$  is the wavelength of the X-ray beam.

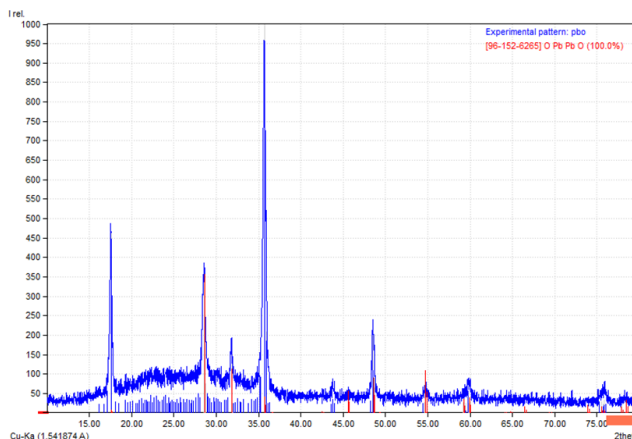


Figure 2: XRD of the prepared thin film (the blue peak) and the reference peak (the red line)

Sample Data	
File name	pbo.bt
Data range	9.950° - 79.950°
Number of points	3501
Step size	0.020
Rietveld refinement converged	No
Alpha2 subtracted	No
Background subtr.	No
Data smoothed	No
2theta correction	-0.05°
Radiation	X-rays
Wavelength	1.541874 Å

Index	Amount (%)	Name
A	100.0	Pb O
	37.7	Unidentified peak area

A: Pb O (100.0 %)	
Formula sum	O Pb
Entry number	96-152-6265
Figure-of-Merit (FoM)	0.815279
Total number of peaks	68
Peaks in range	42
Peaks matched	20
Intensity scale factor	0.36
Space group	P 4/n m m
Crystal system	tetragonal
Unit cell	a = 3.9748 Å c = 5.0227 Å
I/c	28.83
Calc. density	9.339 g/cm <sup>3</sup>

Figure 3: XRD measuring condition and property data of the sample

From the study of the X-ray diffraction pattern and locating the position of the peak as shown in figure 4. After the subjection of the thin film to cold plasma at different times (5, 10, 15, 20, 25) min. It has notice that the peak 002 at 5 min of subjection to the cold plasma has intensity of 1500, but when the treatment time increases to 10 min the intensity of the same peak decreases to 1400, when the time increase to 15 min the intensity decreases to 1200. at subjection time of 20 the intensity was 1100 and at 25 the intensity was 900.for the second peak of 001 there is no significant effect at treatment time of 5 and 10 min and the effect is shown after 15 min of treatment at intensity value of 500 and at 25 min of treatment the intensity decreases to 400. For the rest of the peaks there is no significant change at any time of treatment.

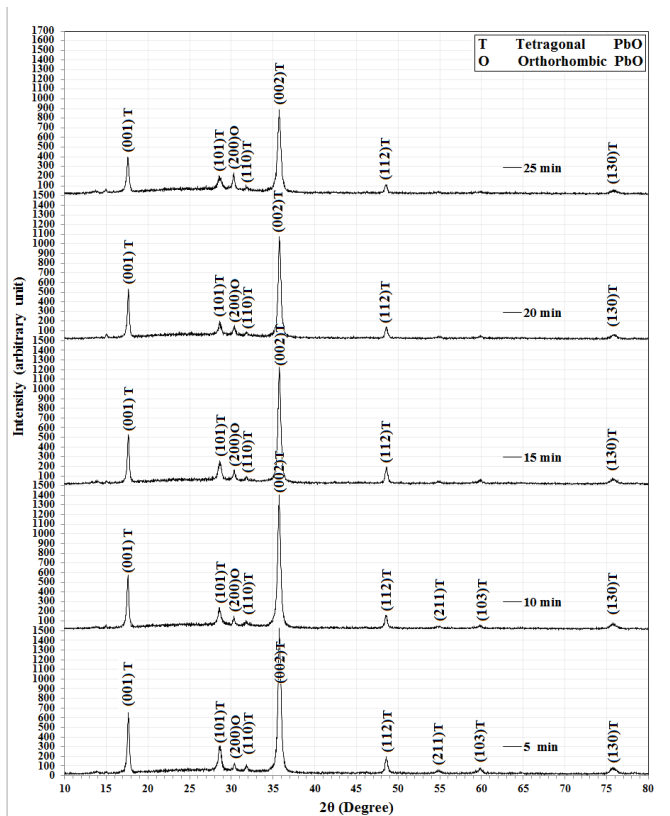


Figure 4: XRD of the thin film after the subjection of the thin film to cold plasma at different times

For all films, the grain size (G.S) was calculated from the full width at half maximum (FWHM) by using the Debye-Scherrer, s equation [64].

$$D = \frac{0.94 \lambda}{\beta \cos \theta} \quad (2)$$

D: The average grain size  
 $\lambda$ : is the X-ray wavelength (Å)  
 $\beta$ : FWHM (radian).  
 $\theta$ : Bragg diffraction angle of the XRD peak (degree)

The grain size (G.S) was calculated using match! Software for the lead oxide (PbO) thin film after the treatment with cold plasma at different times (5,10,15,20,25) min for the peak [(001), (200), (110), (112),(101),(130)].table 1 show the treated thin film at different time with the grain size, at 5 min of treatment the grain size was A 1906.4 and after 10 min treatment the grain size was 670.3 A. at 15 min there is increase in the grain size at value of 3368.4 A. the grain size continue to increase at 15 min treatment at value of 4045.6 A and at 25 min the grain size was 4275.4 A .

Table 1: FWHM and Ave crystallite size calculation

2theta [deg]	I/I0	FWHM	Ave Crystallite size [A]	Time min
30.217	52.4	0.1547		5
31.709	27.6	0.0437		
34.69	21.1	0.0266	1906.4	
35.638	1000	0.0219		
30.313	194.5	0.2272		10
31.835	36.4	0.1224	670.3	
34.749	38.6	0.1063		

35.765	1000	0.1028		15
30.368	79.8	0.1429		
31.858	32.8	0.0423	3368.4	
34.782	3.6	0.0084		
35.024	3.2	0.1659		
30.368	44.6	0.1429		20
31.823	34.4	0.0425		
34.56	15.2	0.0272	4045.6	
35.764	1000	0.0227		
30.357	83.6	0.0123		25
31.83	25.1	-		
34.65	15.1	0.0268	4275.4	
35.762	1000	0.0227		

### B. AFM result

The study of topography of the lead oxide thin film PbO is accomplished by using atomic force microscopy (AFM) device. The AFM image were taken to the thin film after the subjection of the thin film to cold plasma at different times (5,10,15,20,25) min. (Root Mean Square) (RMS) and (Roughness, Sq) are the two parameter that have been considered to study the change in roughness of the thin film after the treatment with cold plasma. Figure 4 Which show the relation between the time of cold plasma treatment both roughness parameter Sq and RMS, as the treatment time of the cold plasma increase the roughness parameter also increase and the largest increment of the roughness start after 20 min of treatment. The result of the AFM also show the average diameter of the thin film as shown in the table 2. The average diameter increase as the time of the treatment increase this behavior is similar to the XRD analysis where the average crystallinity size increase too

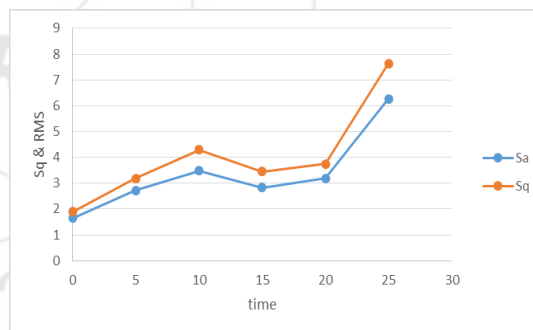


Figure 4: (Root Mean Square) (RMS) and (Roughness, Sq) VS time

Table 1: (Root Mean Square) (RMS) and (Roughness, Sq) at different times of treatment

time	Sq	RMS	Avg. diameter nm
0	1.65	1.9	93.62
5	2.72	3.19	99.56
10	3.49	4.29	126.64
15	2.83	3.45	97.57
20	3.19	3.75	101.18
25	6.26	7.63	109.1

### 4. Consolation

Dielectric barrier discharge is one of the instrument that used to generate cold plasma for the surface modification application. The XRD data has shown that the decrease in the intensity as time of treatment increase indicate a removal of a

very thin layer from the surface of the thin film. The AFM analysis show an increase in the surface roughness as treatment time increase also shows increase in the average diameter of which this behavior is similar to the grain size calculation of the XRD data.

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